TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

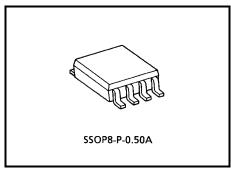
# TC7WBL126AFK

#### Low-Voltage Dual Bus Switch

The TC7WBL126AFK provides two bits of low-voltage high-speed bus switching. The low ON-resistance of the switch allows connections to be made with minimal propagation delay and while maintaining CMOS low power dissipation.

The device comprises dual 2-bit switches with separate bus enable ( $\overline{\text{OE}}$ ) signals. When  $\overline{\text{OE}}$  is high, the switch is on and port A is connected to port B. When  $\overline{\text{OE}}$  is low, the switch is off and a high-impedance state exists between the two ports.

All inputs are equipped with protection circuits to guard against static discharge.

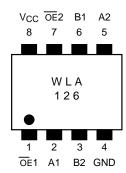


Weight: 0.01 g (typ.)

#### **Features**

- Operating voltage range: VCC = 2 to 3.6 V
- High speed:  $t_{pd} = 0.31 \text{ ns (max)} @ 3 \text{ V}$
- Ultra-low ON-resistance: Ron = 5  $\Omega$  (typ.) @ 3 V
- ESD performance: human-body model > 2000 V; machine model > 200 V
- Power-down protection provided on inputs (OE input only)
- Designed for I<sup>2</sup>C bus interface
- Package: US8

#### Pin Assignment (top view)

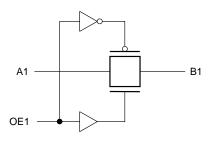


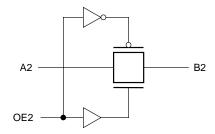


## **Truth Table**

Inputs	Function
OE	Function
Н	A port = B port
L	Disconnect

## **Logic Diagram**





# Maximum Ratings (Ta = 25°C)

Chara	cteristic	Symbol	Rating	Unit	
Power supply range	ge	V <sub>CC</sub>	-0.5~4.6	V	
Control pin input v	oltage	V <sub>IN</sub>	-0.5~4.6	V	
Switch terminal I/O voltage		Vs	-0.5~Vcc+0.5	V	
Clump diode	Control input pin	luz	-50	mA	
current	Switch terminal	lık	±50		
Switch I/O current		IS	128	mA	
Power dissipation		PD	200	mW	
DC V <sub>CC</sub> /GND current		I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature		T <sub>stg</sub>	-65~150	°C	

# **Recommended Operating Conditions**

Characteristic	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	2.0~3.6	V
Control pin input voltage	V <sub>IN</sub>	0~3.6	V
Switch I/O voltage	Vs	0~Vcc	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

2

#### **Electrical Characteristics**

#### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristic	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level control input voltage	V <sub>IH</sub>	_	2.0 to 3.6	0.7 × V <sub>CC</sub>	_	_	V
Low-level control input voltage	V <sub>IL</sub>	_	2.0 to 3.6	_	_	0.3 × V <sub>CC</sub>	V
Control input current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V	2.0 to 3.6	_	_	±1.0	μА
Power off leakage current	l <sub>OFF</sub>	OE = 0 to 3.6 V	0	_	_	±1.0	μА
Off-stage leakage current (switch off)	I <sub>SZ</sub>	A, B = 0 to $V_{CC}$ , $\overline{OE}$ = GND	2.0 to 3.6	_	_	±1.0	μА
		$V_{IS} = 0 \text{ V}, I_{IS} = 30 \text{ mA}$ (Note 1	) 3.0	_	2	7	
		$V_{IS} = 3.0 \text{ V}, I_{IS} = 30 \text{ mA}$ (Note 1	) 3.0	_	4	9	
Switch ON-resistance	D	$V_{IS} = 2.4 \text{ V}, I_{IS} = 15 \text{ mA}$ (Note 1	) 3.0	_	5	15	0
(Note 2)	R <sub>ON</sub>	$V_{IS} = 0 \text{ V}, I_{IS} = 24 \text{ mA}$ (Note 1	) 2.3	_	3	10	Ω
		$V_{IS} = 2.3 \text{ V}, I_{IS} = 24 \text{ mA}$ (Note 1	) 2.3	_	5	15	
		$V_{IS} = 2.0 \text{ V}, I_{IS} = 15 \text{ mA}$ (Note 1	) 2.3	_	8	25	
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	3.6	_	_	10	μА

Note 1: All typical values are at  $Ta = 25^{\circ}C$ .

Note 2: Measured by voltage drop between A and B pins at indicated current through the switch. ON-resistance is determined by the lower of the voltages on the two pins (A or B).

# AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristic	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay (bus to bus)	t <sub>pLH</sub>	Figure 1, Figure 2 (Note 3)	$3.3 \pm 0.3$	_	0.31	ns
r ropagation delay (bus to bus)	t <sub>pHL</sub>	(Note 3)	$2.5 \pm 0.2$	_	0.52	115
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	$3.3 \pm 0.3$		7	ns
Output enable time	t <sub>p</sub> ZH	rigure 1, rigure 3	$2.5 \pm 0.2$		10	2
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	$3.3 \pm 0.3$		8	ns
Output disable time	t <sub>pHZ</sub>		$2.5 \pm 0.2$	_	9	113

Note 3: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical ON-resistance of the switch and the 50 pF load capacitance when driven by an ideal voltage from the source (zero output impedance).

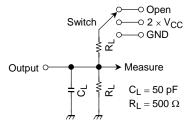
#### Capacitance (Ta = 25°C)

Characteristic	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control input capacitance	C <sub>IN</sub>		3.0	3	pF
Switch terminal capacitance	C <sub>I/O</sub>	OE = GND	3.0	23	pF

3

#### **AC Test Circuit**

**TOSHIBA** 



Test	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
$t_{pLZ}, t_{pZL}$	2 × V <sub>CC</sub>
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND

Figure 1

#### **AC Waveforms**

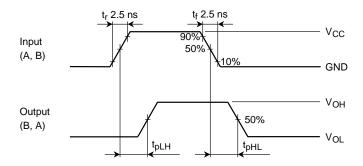


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

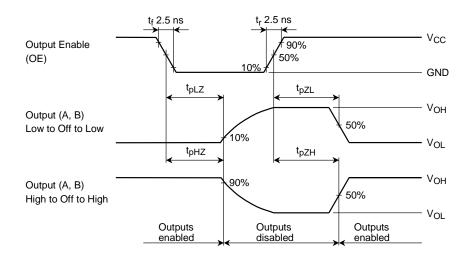
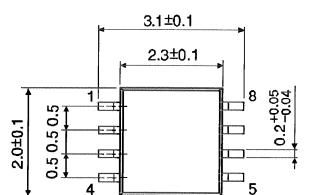


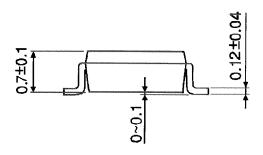
Figure 3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

# **Package Dimensions**

SSOP8-P-0.50A



Unit: mm



Weight: 0.01 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

030619EBA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor
  devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
  stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of
  safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of
  such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
   In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as
  - set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.